

LOW INTENSITY ULTRA BRIGHT ELECTRON SOURCE

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CBP AFRD LBNL



Erice, Sicily Workshop 10/11/05
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Working Group

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Brightness & Degenerate Parameter

$$dN = \frac{dx dp_x dy dp_y dz dp_z}{h^3}$$

$$dN = \frac{dx d\beta_x dy d\beta_y dz d\beta_z}{(2\pi)^3 \lambda_C^3}$$

$$N = \frac{\epsilon_x \epsilon_y \epsilon_z}{\lambda_C^3} \quad \lambda_C = 3.86 \cdot 10^{-11} \text{ cm}$$

Number of particles per elementary volume

$$\delta_F = \frac{N_\phi}{N} = \frac{N_\phi}{\epsilon_x \epsilon_y \epsilon_z} \lambda_C^3 = B \lambda_C^3$$

For fermions Pauli exclusion principle limit value of δ_F
 $\delta_F < 1$

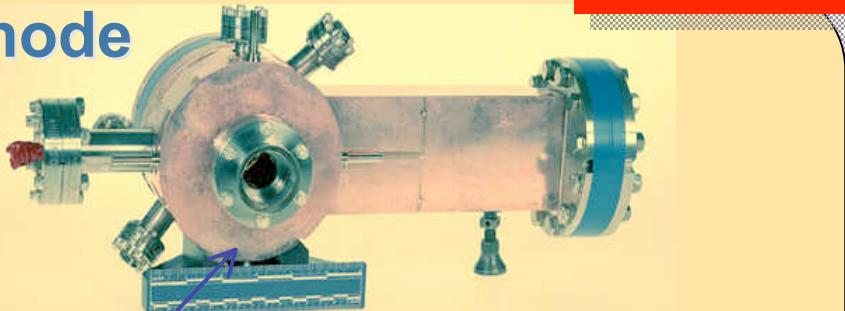
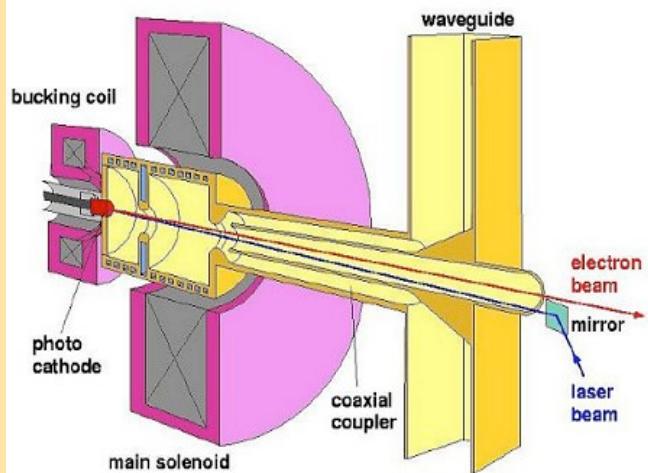
In copper $\delta_F = .995$



High intensity sources (10-100 A)

$$\delta_F \sim 10^{-12}$$

RF Gun with Photocathode



ATF (BNL) Gun III (LINAC Injector):

- Energy ~ 2 MeV
- Normalized rms emittance of 2.6 mm mrad
- Charge of 1 nC
- Pulse length of 10 ps
- RF = 2856 MHz (1 MV/cm)

Charge densities up to 10^5 A/cm²

Gun for LCLS



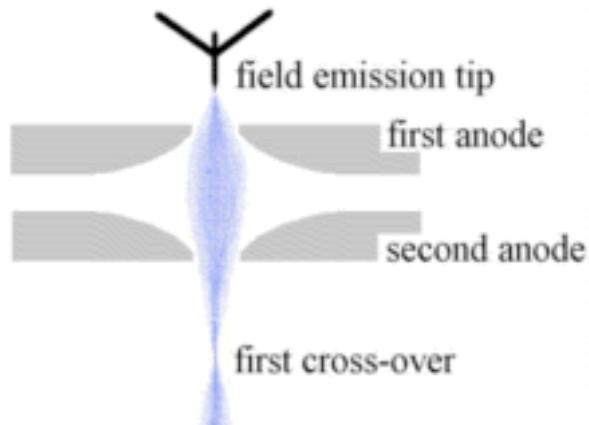
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$$\delta_F \sim 4 \cdot 10^{-12}$$

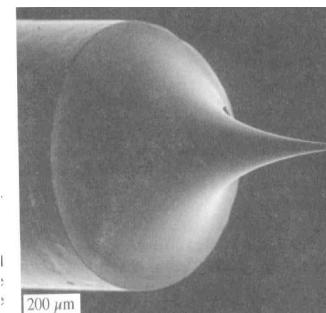
Low intensity sources (1-10 nA)

Field Emission Electron Gun

Field Emission Gun



V. V. Kabanov, Institute of Nuclear Physics, Novosibirsk, Russia



THERMO Electro Corporation:

- Field at the cathode tip ~ 10 MV/cm
- 100 nm spot size at 5 nA sample current
- Current density ~ 50 A/cm²
- Application: Electron microscope

Current densities on sample up to 10⁵ A/cm²

$$\delta_F \sim 5 \cdot 10^{-7}$$

Electron effective temperature
kT_e ~ .15 - .2 eV

Modern developments
including “nanotube”

$$\delta_F \sim 5 \cdot 10^{-6}$$



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Main ideas

$$\text{Cs}^{133} \quad kT_{\text{Cs}} \sim 26 \text{ meV}$$

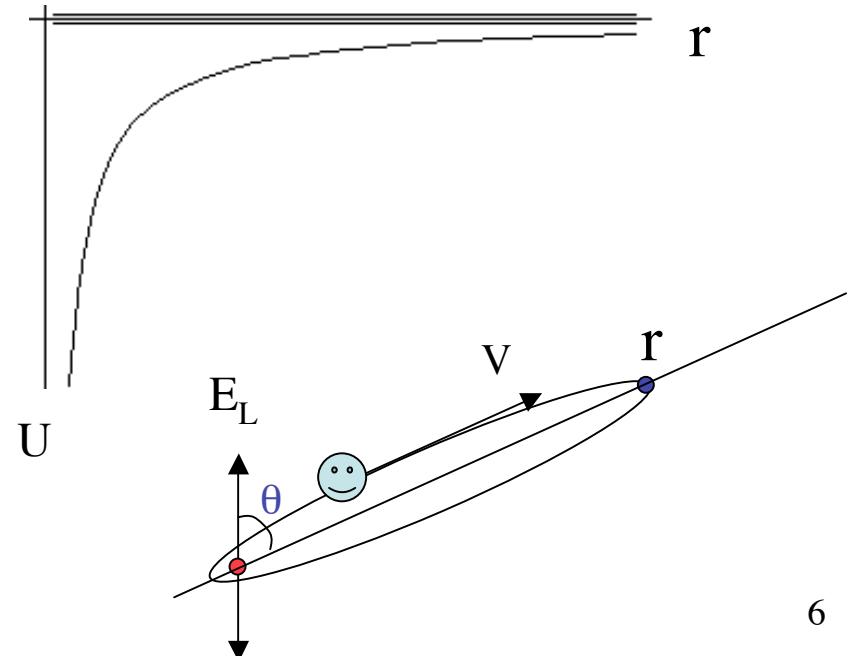
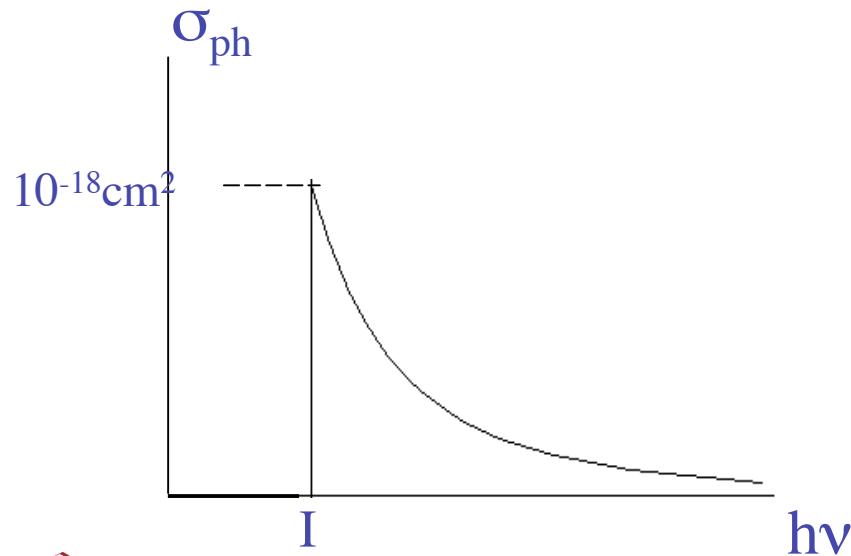
$$kT_e \sim 26 \text{ meV} \quad m_e/M_{\text{Cs}} \sim 10^{-7} \text{ eV}$$

Plasma with hot ions and
extremely cool electrons

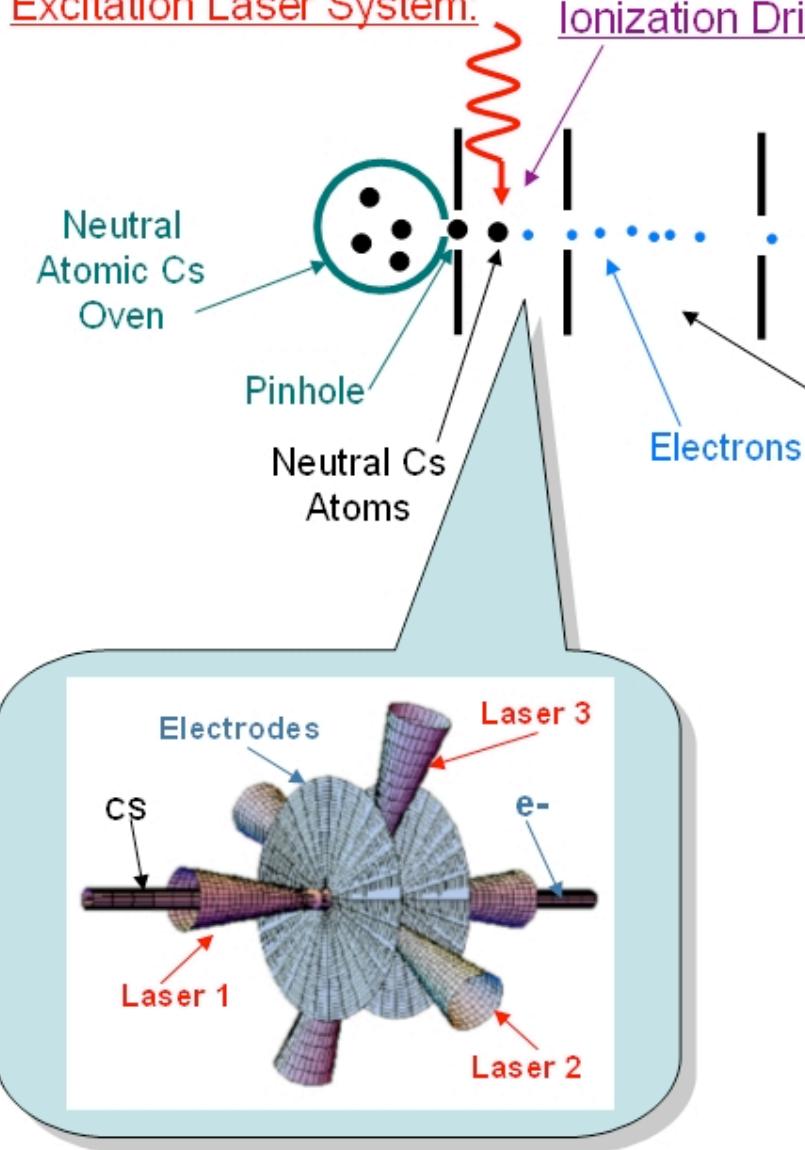
Compare with
 $kT_e \sim .15 - .2 \text{ eV}$

Problems: space charge when one tries to separate electrons and ions

Solution: make electrons one by one low intensity (< 1 pA)
high brightness



Excitation Laser System:



Ionization Drift (ID):

Electron Energy Analyzer
1 mV resolution
(ALS Scienta or
time of flight type)

Energy Matcher (EM):
Matches energy of the Energy Analyzer

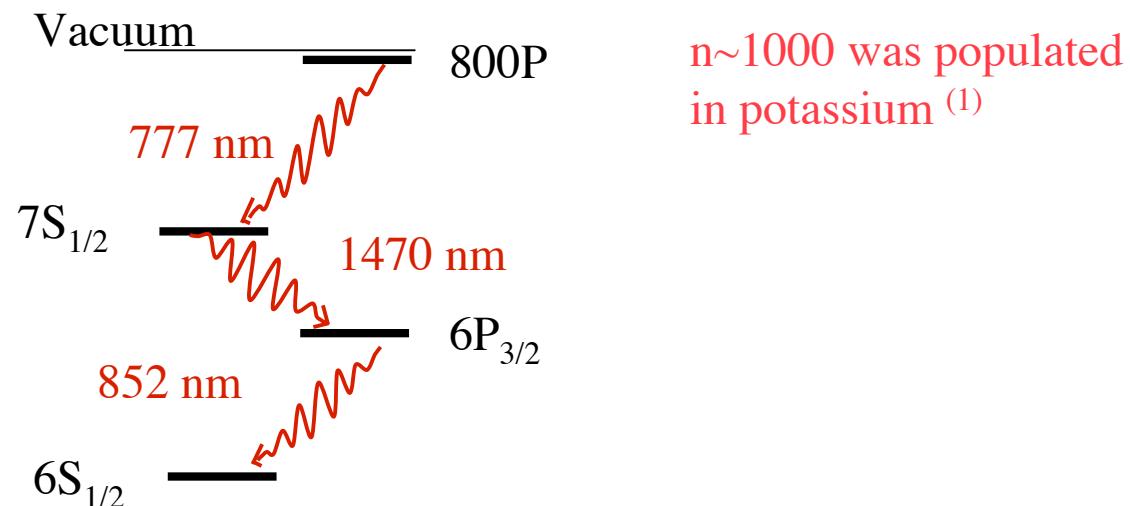
NOT TO SCALE

Timing:



Electron Excitation

In the interaction region, defined by the overlap of the Lasers and atomic beam, we excite on average one Cs atom per laser pulse to a Rydberg state very close to vacuum ($\sim 10^{-5}$ eV). The electron in the excited atom will have a large kinetic energy and will start to move from the ion.



Waiting Period

After the laser pulse, we wait the time necessary (~ 40 ns) for the electron to go far from the nucleus (~ 65 μm) and reach the turning point of its classical orbit where its kinetic energy is negligible. At this point, a short pulsed voltage ionizes the atom, extracts the electron from the interaction region.



Electron Acceleration

DC voltage applied between next electrodes accelerates electron to desired energy.

Ion Clearing

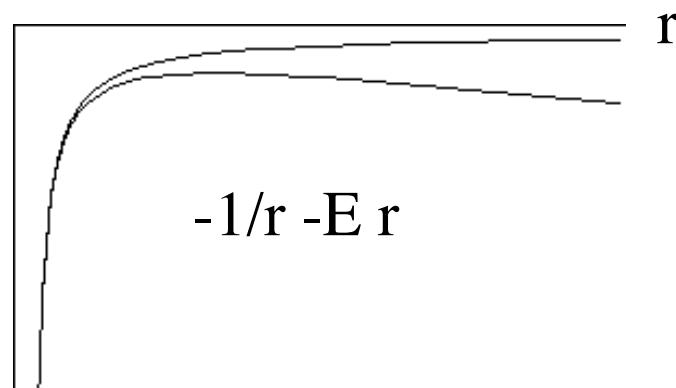
After the electron leaves the second region, a “clearing” pulsed field removes the residual ion before the beginning of the following cycle. In this way the electron produced in the next cycle does not interact with ions from previous pulses.



Residual Magnetic and Electric Fields

**Magnetic field $\sim 10^{-3}$ Gauss will degrade brightness.
The source needs to be contained within suitable
magnetic shielding. (2 layers of μ metal shield)**

**For $n \sim 800$ stray electric fields need to be constrained
within 10^{-4} V/cm. (Schottky-barrier lowering)**



Expectations

Semiclassical treatment:

$$\epsilon_{x,y} = \frac{1}{2} \sqrt{(n \Omega \tau)^2 + \left(\frac{3\pi}{2\Omega\tau}\right)^2} \langle \sin^2 \theta \rangle \langle \sin^2 \varphi \rangle$$

For Cs; $w \sim 1+3 \cos^2 \theta$;

$$\langle \sin^2 \theta \rangle \langle \sin^2 \varphi \rangle = 4/15$$

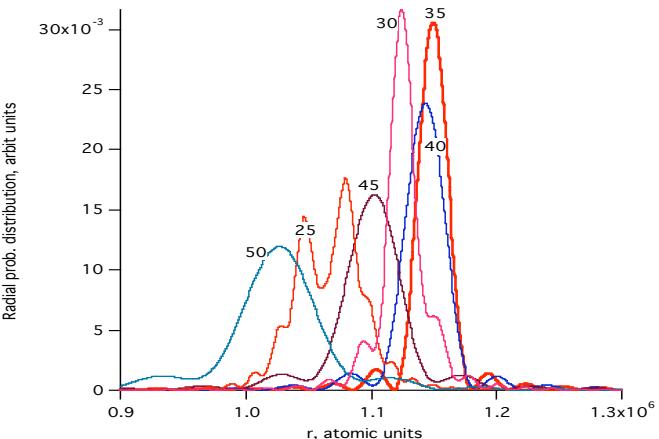
For $n=800$, optimum $\tau = 1$ ns

and

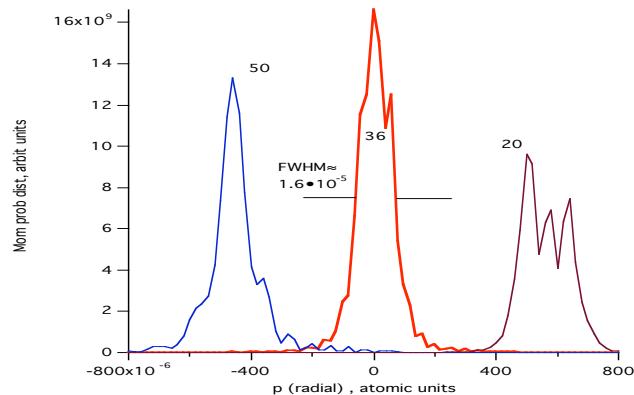
$$\epsilon_{x,y} = 2/15 \sqrt{3\pi n} \sim 11.5$$

$$\delta_F \sim 10^{-3}$$

Quantum treatment (E.D. Commins)



Radial wave-packets for $t=25, 30, 35, 40, 45$, and 50 ns after initiation of Gaussian laser pulse, centered on $7s-759p$ transition.



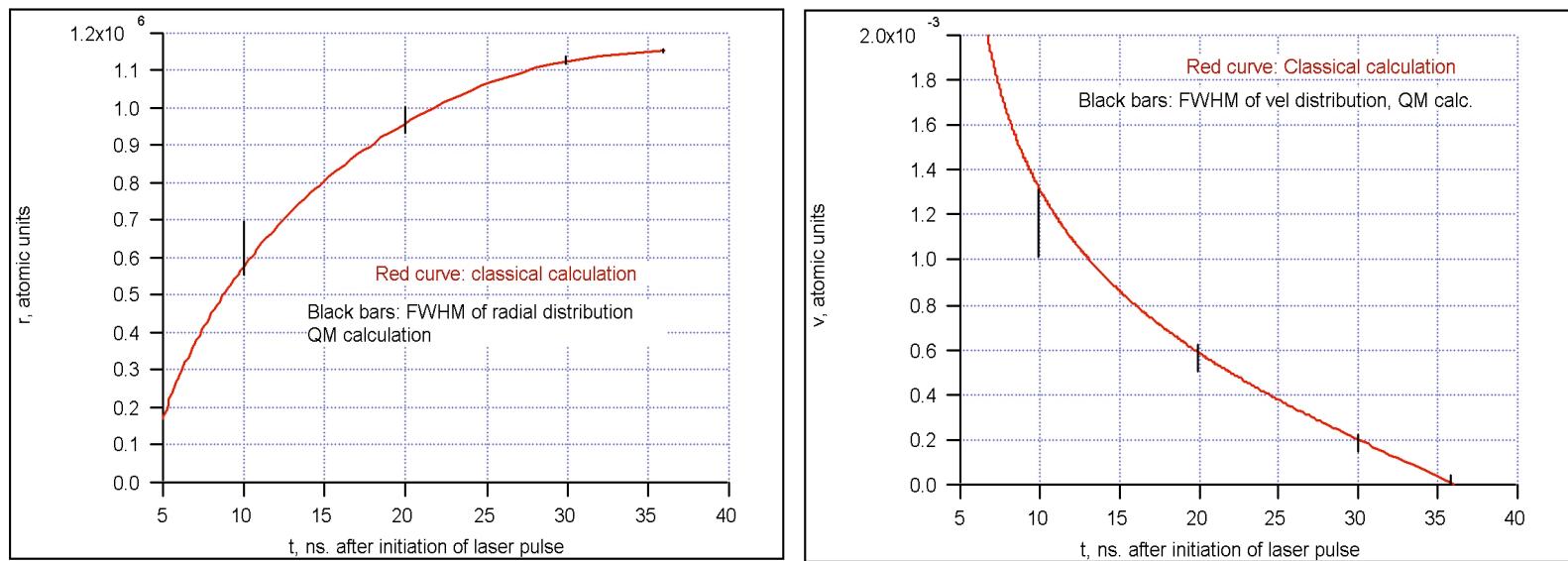
Radial momentum distributions for $t=20, 36$, and 50 ns after initiation of the laser pulse.

$$\epsilon_{x,y} \sim 12$$

12

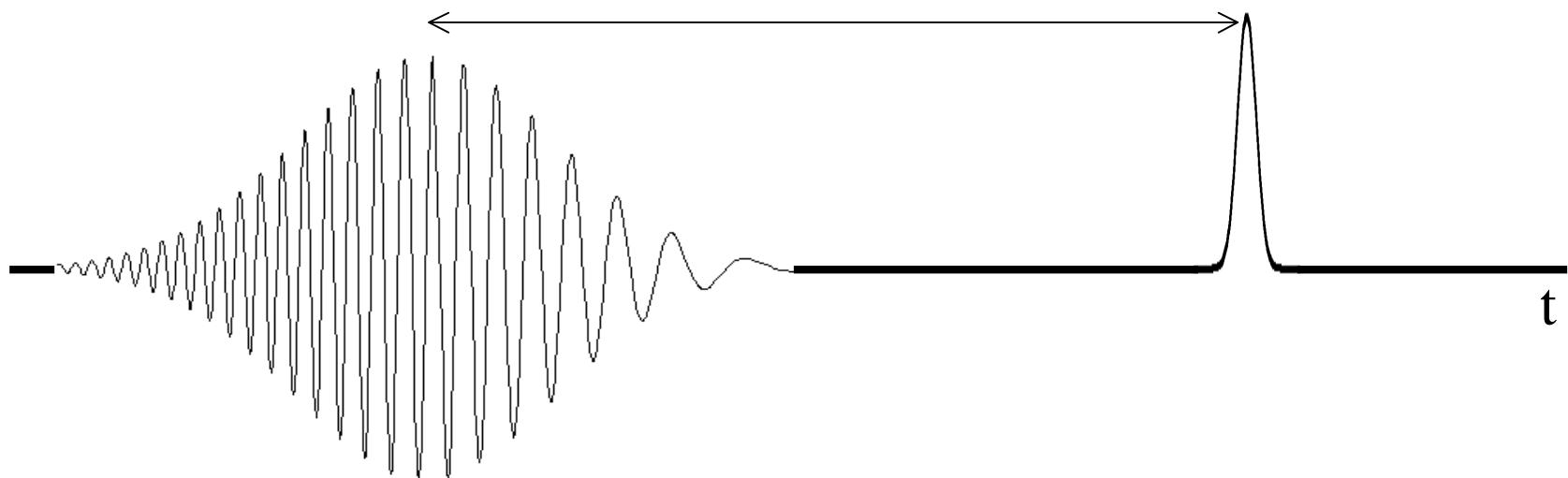


Quantum calculation (E.D. Commins)



Chirp pulse excitation

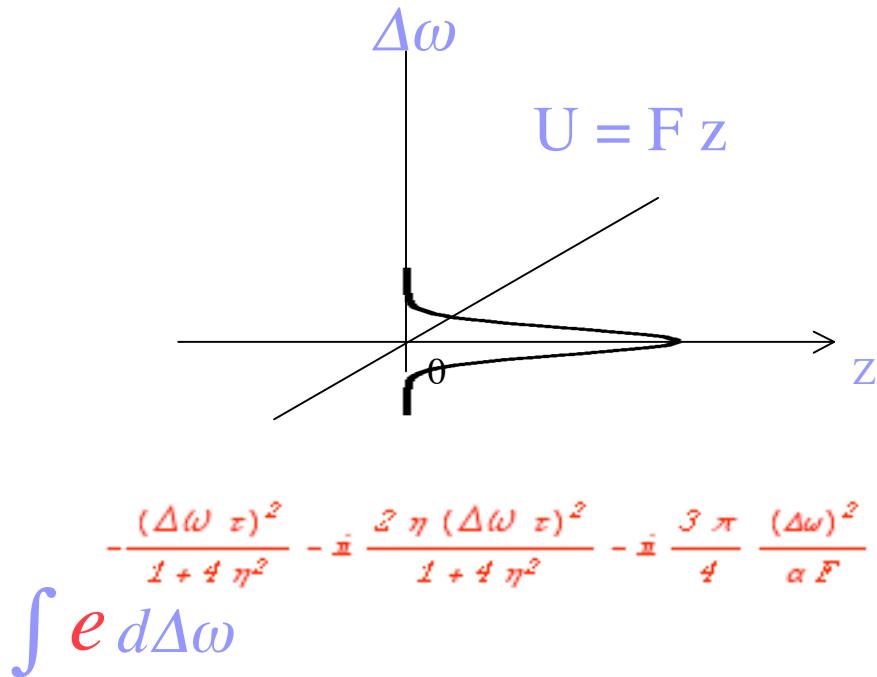
40 ns



$$\epsilon_{x,y} = \frac{1}{2} \sqrt{(n\Omega\tau)^2 + \left(\frac{3\pi}{\Omega\tau}\right)^2} \langle \sin^2 \theta \rangle \langle \sin^2 \phi \rangle$$



Quantum Picture of Chirp Pulse Excitation

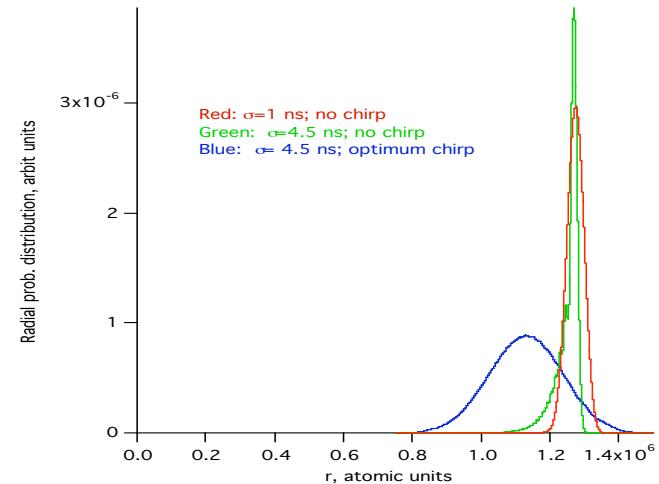


$$\epsilon_{x,y} = \frac{3\pi}{4\Omega\tau} \langle \sin^2 \theta \rangle \langle \sin^2 \varphi \rangle$$

$$\epsilon_{x,y} \sim 1$$

$\epsilon_{x,y} = 2$; including initial source size
and atomic velocity spread

$$\delta_F \sim .1$$

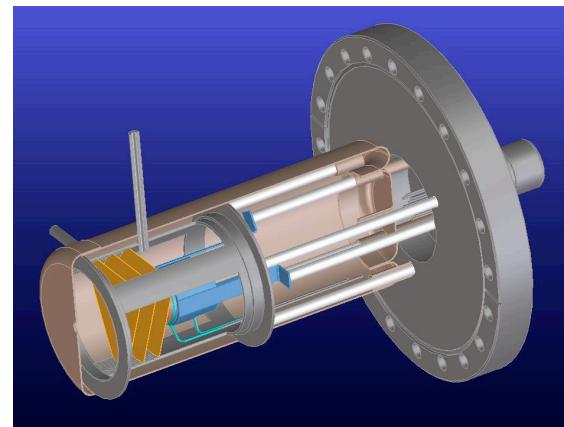
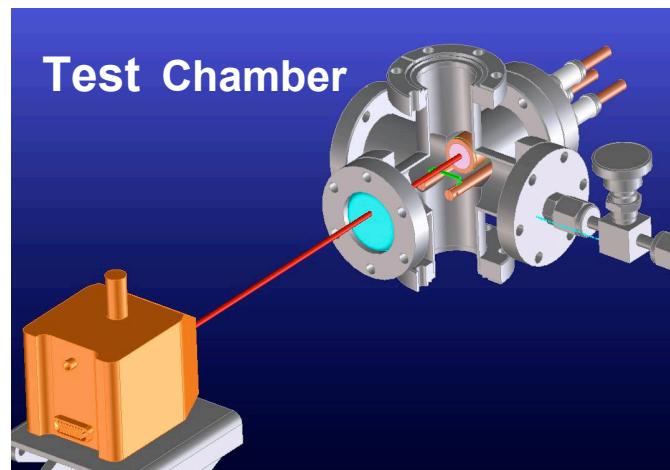
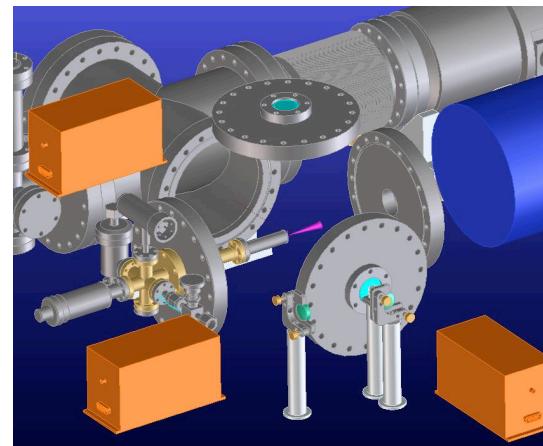
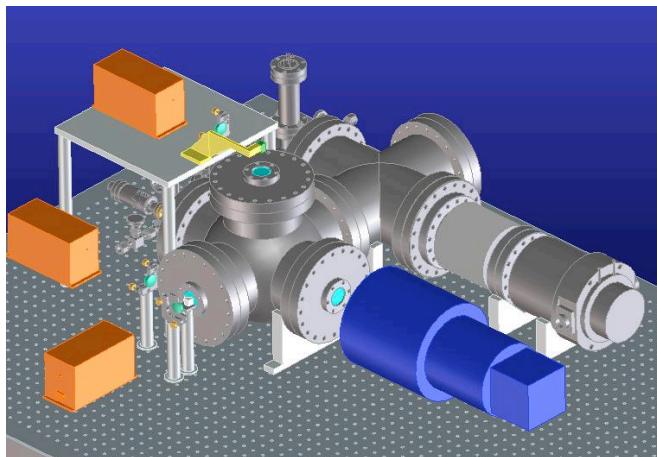


E.D.Commins numerical calculations



We are really doing it

Two years LDRD project
\$130 k and \$130 k



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Main problems

Known:

- Stray fields
 - Electric patch fields $< 10^{-4}$ V/cm
 - Magnetic fields $< 10^{-3}$ Gauss
- Photo-ionization by laser light scattered on electrode surfaces: > 777 nm; cesium coating of surfaces
- Mirror charge problems (very low energy and energy spread of electrons)
- Electronics problems: Short intense electric field pulses: (ringing problems)
- Aberrations

Unknown?

In principle, each problem can be solved,
but perhaps not in my lifetime.

